UNIVERSITY OF PETROLEUM AND ENERGY STUDIES End Semester Examination, May 2018

Course: Physics II Course Code: PHYS1004 Program: B.Tech (SOE) Time: 03 hrs. Semester: II

Max. Marks: 100

Instructions:

- 1. All questions are compulsory.
- 2. This question paper has three sections; Section A, Section B, and Section C
- 3. In section A there are total 5 questions, each carrying 4 marks
- 4. In Section B there are total 4 questions, each carrying 10 marks. Question no. 9 is having an internal choice.
- 5. In Section C there are total 2 questions, each carrying 20 marks. Question no. 11 is having internal choice.
- 6. Draw suitable diagrams wherever required.
- 7. Your answer should be concise and to the point.
- 8. The CO's represents Course Outcomes which are for official purpose.

| | SECTION A | | |
|--------|--|--------|-----|
| S. No. | | Marks | CO |
| Q 1 | Deduce the expression for time dilation using the Lorentz transformation equations. | 4 | CO1 |
| Q 2 | Estimate the energy of the electrons that we need to use in an electron microscope to resolve a separation of 0.27nm. | 4 | CO2 |
| Q 3 | Discuss the basic assumption of Planck's radiation law for black body radiations. (<i>Maximum 50 words</i>). | 4 | CO1 |
| Q 4 | Illustrate that in a system of fermions at T=0 K, all the states of $E \le E_F$ are occupied and all states $E \ge E_F$ are unoccupied. | 4 | CO1 |
| Q 5 | Define Bohr magneton. Discuss the temperature variation of paramagnetic and diamagnetic susceptibilities of materials. | 4 | CO1 |
| | SECTION B | | |
| Q 6 | i. Discuss the classical and quantum approach to explain specific heat of solids. Derive the formula for specific heat of solids using quantum approach (Einstein Formula). ii. A Ge semiconductor diode carries a current of 1 mA at room temperature when a forward bias of 0.15 V is applied, estimate the reverse saturation current at room temperature. | 5 5 | CO2 |
| Q 7 | Explain various polarization mechanisms in a non-polar dielectric. For a dielectric material with $\epsilon_r = 3.6$ and $D = 285 nC m^{-2}$, find the magnitudes of E , $P \wedge \chi_e$. | 5+5 | CO2 |
| Q 8 | i. A square of area 100 cm ² is at rest in the frame of reference of S. Observer S' | 5+5 | CO3 |

| | moves relative to S at 0.8c and parallel to one side of the square. Determine the area as measured by S' observer. | | |
|----------|---|-----|---------|
| | ii. Consider an intrinsic Si (density=2.33 gm i , $n_i = 1.5 \times 10^{16} m^{-3}$, atomic weight = | | |
| | 28.09 <i>amu</i>) with electron mobility $\mu_n = 0.135 m^2 V^{-1} s^{-1}$. If the Si is doped with | | |
| | one pentavalent impurity for each 10^7 Si atoms. Determine the concentration of | | |
| | electrons (n), holes (p) and conductivity (σ). | | |
| Q 9 | Derive an expression for allowed energies for a particle in one-dimensional box of length L (infinite potential barrier). Write the normalized wave function and sketch the allowed wave-functions and probability densities for $n=1$, 2 and 3. | 10 | |
| | OR | | |
| | i. Discuss the essential properties of a "well behaved" wave function, representing a quantum-mechanical object. | | CO2 |
| | ii. For pair production to occur charge, momentum and energy should be conserved. Considering only charge and energy conservation, will it be | 5+5 | |
| | possible for pair- production to occur in empty space? | | |
| | SECTION-C | | |
| Q 10 (a) | Define anti-ferroelectricity and ferroelectricity. Obtain the relationship between the | | |
| - () | macroscopic dielectric constant and polarizabilities (Clausis-Mosotti equation) | 4.0 | ~ ~ ~ ~ |
| | using internal (Lorentz) field at an atom in cubic structure $\left(E_L = E + \frac{P}{3\epsilon_0}\right)$. | 10 | CO3 |
| Q 10 (b) | i. The sun mass is $2.0 \times 10^{30} Kg$, its radius is $7.0 \times 10^8 m$, and its surface | | |
| | temperature is $5.8 \times 10^3 K$. How many years are needed for the sun to lose | | |
| | 0.02% of its mass by radiation? | 5+5 | CO4 |
| | ii. The density of Aluminium (Al) is 2.7 gm cm⁻³ and its atomic mass is 26.97 a.m.u. The Al ions in metal are in Al⁺³ states and the effective mass of an electron in Al is 0.97 m_e. Calculate its Fermi Energy in eV. | | |
| Q 11 | i. Using suitable diagram explain the phenomenon of Hall Effect. Also, find the | 10 | CO3 |
| | expression for Hall Coefficient, $R_{H} = \frac{V_{H}b}{IB}$, | 10 | |
| | where V_H =Hall voltage, I = current, B= applied magnetic field, and b is dimension along the direction of applied magnetic field. Highlight any two applications. | | |
| | ii. A photon of energy 4.25 eV strikes the surface of a metal A , the ejected photoelectrons have kinetic energy, KE_A eV and de-Broglie wavelength λ_A . | 10 | |

| | The maximum KE of photoelectrons | iberated from another metal B by the | |
|------------------|---|---|------------------------|
| | photon of energy 4.7 eV is $KE_B = (KE_A)$ | - 1.5) eV. If the de-Broglie wavelength | |
| | of these photoelectrons is $\lambda_B = 2\lambda_A$, then | what are the kinetic energies (KE _A and | |
| | KE _B) of ejected photoelectrons and wor | k functions of two metals? | |
| | OF | t. | |
| i. | | orward and reverse bias. Describe the | 10 |
| ii. | Write the Lorentz transformation equipsimultaneous in both space and time (h in an inertial frame will also be simultarelative to it. | appening at same time and same place) | 10 |
| Values of some | e physical constants: | | |
| Velocity of ligh | $t, c = 3 \times 10^8 m s^{-1}$ | Charge of electron, $e = 1.6 \times 10^{-19} C$ | |
| Mass of electro | $n_{e} = 9.1 \times 10^{-31} kg;$ | Mass of proton/neutron =1 a.m.u.¿ 1.67 | $7 \times 10^{-27} kg$ |
| Boltzmann Cor | stant (K _B) = $1.38 \times 10^{-23} J K^{-1}$ | Planck's Constant (h) = 6.6×10^{-34} Jse | c; |
| Permittivity of | free space $(\epsilon_0 i = 8.854 \times 10^{-12} F m^{-1})$ | Permeability of free space $(\mu_0 \dot{\iota} = 4\pi \times$ | $10^{-7} H m^{-1}$ |
| | ann constant (σ)= 5.67 × 10 ⁻⁸ W m ⁻² K ⁻⁴ | | |

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| | OR |
|---|--|
| tion with suitable | (a) Discuss electronic, ionic, orientati diagram. |
| $\begin{array}{c c} \text{ration of } 10^{21} \ /\text{m}^3 \text{ to} \end{array} \begin{array}{c c} 10 & \mathbf{CC} \end{array}$ | (b) Si is doped with pentavalent impurit |
| | make Si n-type. Calculate conductivi electron is 10 ⁴ m/s for an applied elect |
| | lues of some physical constants: |
| lectron, $e = 1.6 \times 10^{-19} C$ | elocity of light, $c = 3 \times 10^8 m s^{-1}$ |
| ton/neutron =1 a.m.u. $\frac{1}{6}$ 1.67 × 10 ⁻²⁷ kg | ass of electron, $m_e = 9.1 \times 10^{-31} kg;$ |
| nstant (h) = 6.6×10^{-34} Jsec; | ltzmann Constant (K _B) =1.38 × $10^{-23} J K^{-1}$ |
| v of free space $(\mu_0 \dot{c} = 4 \pi \times 10^{-7} H m^{-7})$ | rmittivity of free space ($\epsilon_0 \dot{\iota} = 8.854 \times 10^{-12} F m^{-1}$ |
| | efan-Boltzmann constant (σ)= 5.67 × 10 ⁻⁸ W m ⁻² K |
| 10 KV /m. lectron, $e = 1.6 \times 10^{-19} C$ ton/neutron =1 a.m.u.; 1.67×10^{-27} nstant (h) = $6.6 \times 10^{-34} Jsec$; | electron is 10^4 m/s for an applied elect alues of some physical constants: elocity of light, $c=3 \times 10^8 m s^{-1}$ ass of electron, $m_e=9.1 \times 10^{-31} kg$; eltzmann Constant (K _B) =1.38 × $10^{-23} J K^{-1}$ rmittivity of free space ($\epsilon_0 i = 8.854 \times 10^{-12} F m^{-1}$ |